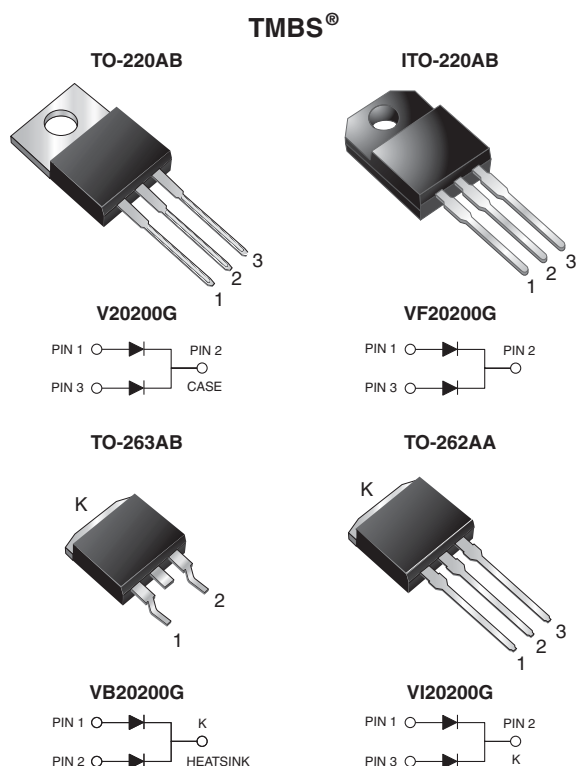


Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.62 \text{ V}$ at $I_F = 5 \text{ A}$



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 10 A
V_{RRM}	200 V
I_{FSM}	110 A
V_F at $I_F = 10 \text{ A}$	0.71 V
$T_J \text{ max.}$	150 °C
Package	TO-220AB, ITO-220AB, TO-263AB, TO-262AA
Diode variations	Common cathode

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	V20200G	VF20200G	VB20200G	VI20200G	UNIT
Max. repetitive peak reverse voltage	V _{RRM}	200				V
Max. average forward rectified current (fig. 1)	I _{F(AV)} per device per diode	20				A
		10				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	110				A
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH per diode	E _{AS}	60				mJ
Peak repetitive reverse current at t _p = 2 μs, 1 kHz, T _J = 38 °C ± 2 °C per diode	I _{RRM}	0.5				A
Voltage rate of change (rated V _R)	dV/dt	10 000				V/μs
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500				V
Operating junction and storage temperature range	T _J , T _{STG}	- 40 to + 150				°C



ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	I _R = 1.0 mA	T _J = 25 °C	V _{BR}	200 (min.)	-	V
Instantaneous forward voltage per diode ⁽¹⁾	I _F = 5 A	T _J = 25 °C	V _F	0.86	-	V
	I _F = 10 A			1.23	1.70	
	I _F = 5 A	T _J = 125 °C		0.62	-	
	I _F = 10 A			0.71	0.80	
	Reverse current per diode ⁽²⁾	V _R = 180 V		T _J = 25 °C	I _R	
T _J = 125 °C			1.6	-		mA
V _R = 200 V		T _J = 25 °C	-	150		μA
		T _J = 125 °C	2.5	15		mA

Notes(1) Pulse test: 300 μs pulse width, 1 % duty cycle(2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)						
PARAMETER	SYMBOL	V20200G	VF20200G	VB20200G	VI20200G	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	3.2	5.5	3.2	3.2	$^{\circ}\text{C/W}$

ORDERING INFORMATION (EXAMPLE)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	V20200G-E3/4W	1.88	4W	50/tube	Tube
ITO-220AB	VF20200G-E3/4W	1.75	4W	50/tube	Tube
TO-263AB	VB20200G-E3/4W	1.39	4W	50/tube	Tube
TO-263AB	VB20200G-E3/8W	1.39	8W	800/reel	Tape and reel
TO-262AA	VI20200G-E3/4W	1.45	4W	50/tube	Tube

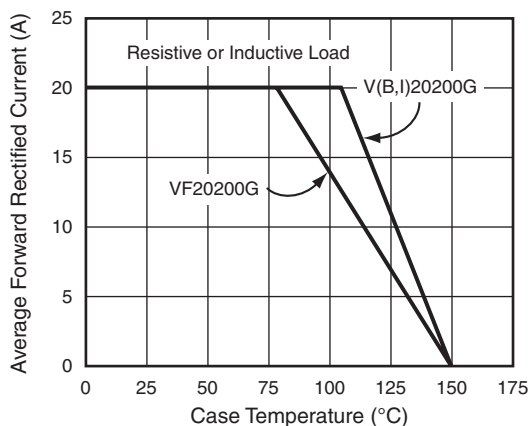
RATINGS AND CHARACTERISTICS CURVES($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

Fig. 1 - Maximum Forward Current Derating Curve

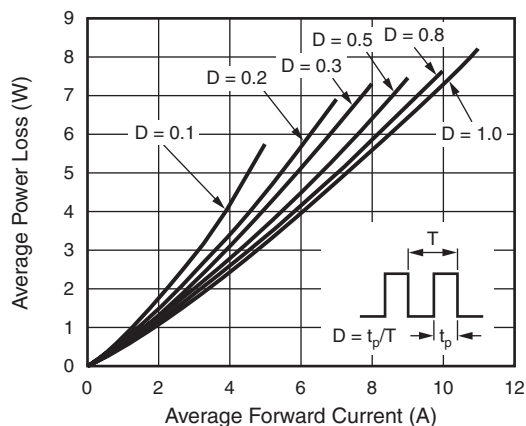


Fig. 2 - Forward Power Loss Characteristics Per Diode

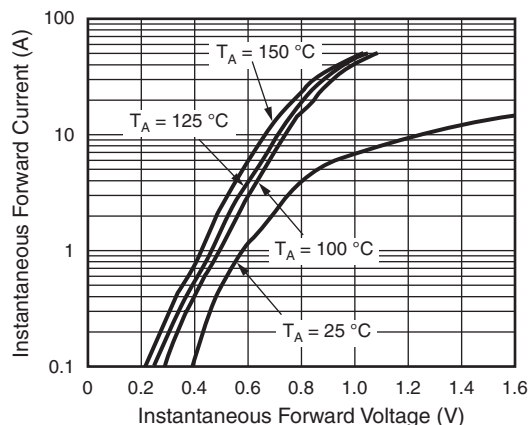


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

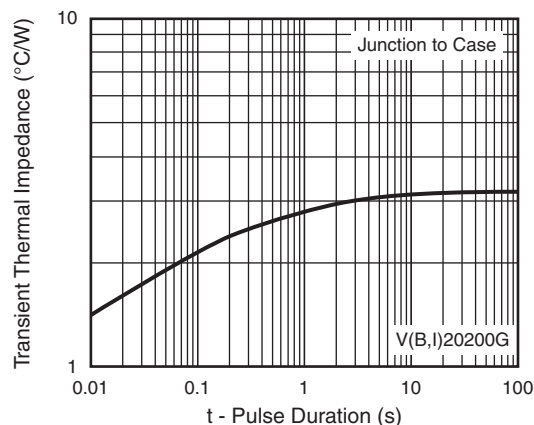


Fig. 6 - Typical Transient Thermal Impedance Per Diode

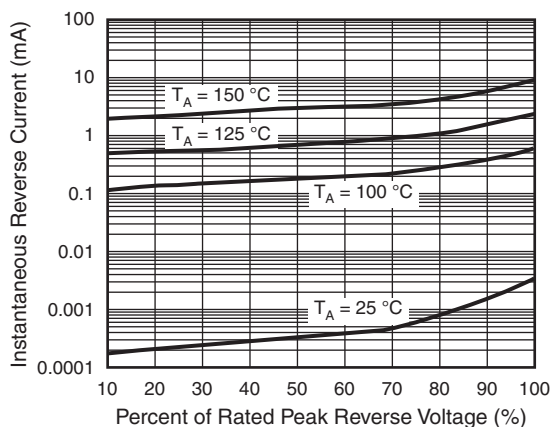


Fig. 4 - Typical Reverse Characteristics Per Diode

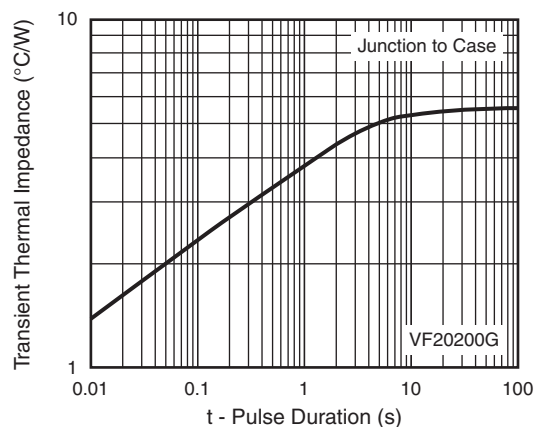


Fig. 7 - Typical Transient Thermal Impedance Per Diode

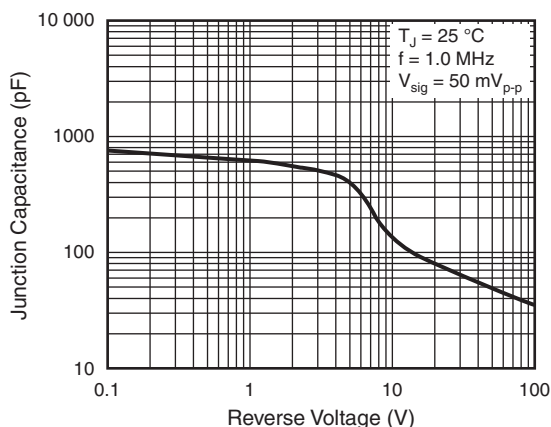
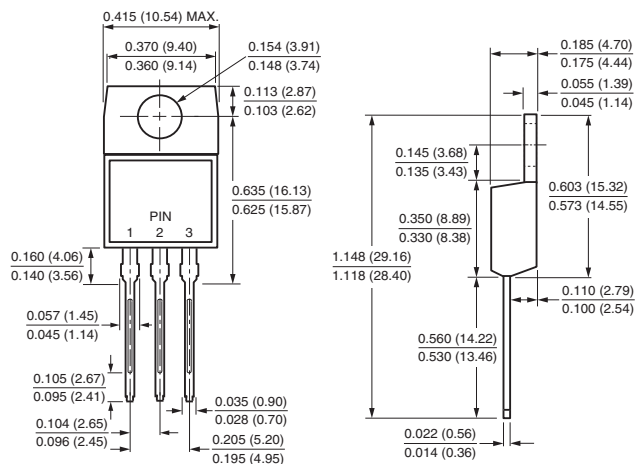


Fig. 5 - Typical Junction Capacitance Per Diode

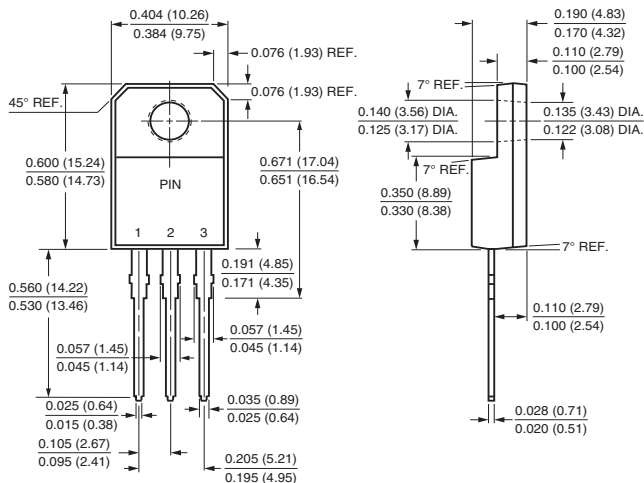


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

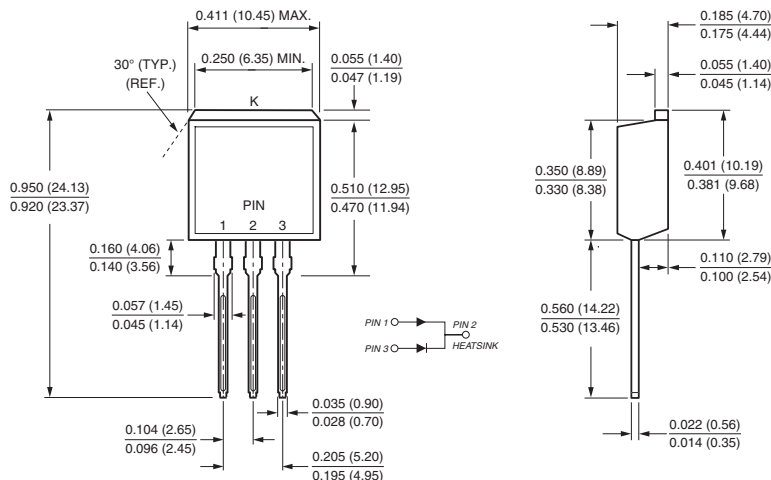
TO-220AB



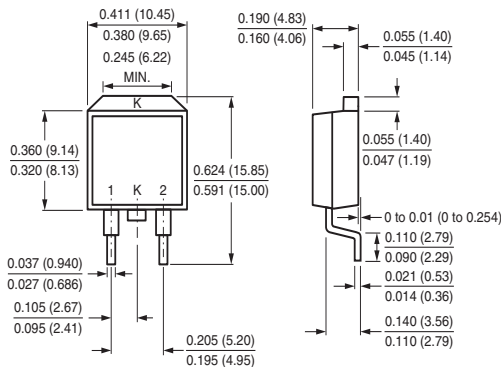
ITO-220AB



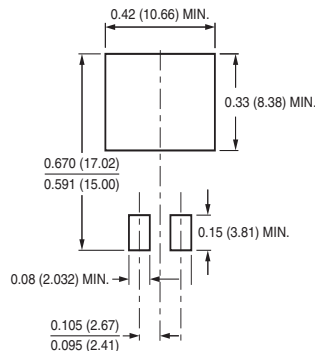
TO-262AA



TO-263AB



Mounting Pad Layout





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